Preliminary

SGL-0363Z

RoHS Compliant & Green Package

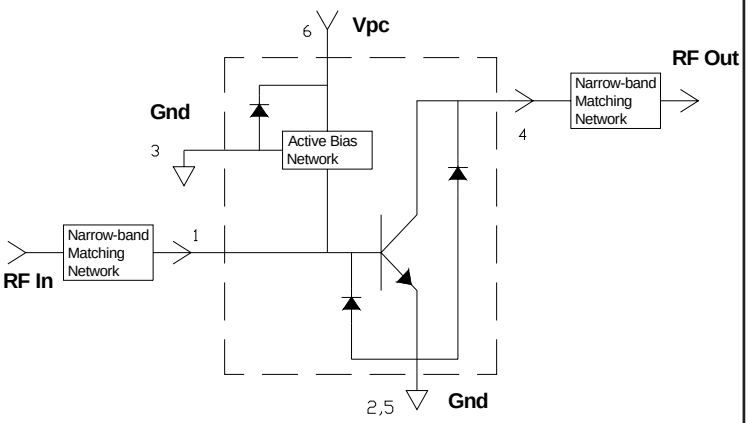
5-2000 MHz Low Noise Amplifier
Silicon Germanium

Product Description

Sirenza Microdevices' SGL-0363Z is a low power, low noise amplifier. It is designed for 2.7 to 3.3V battery operation. The matching networks are implemented externally which allows for optimum narrow-band performance with 20dB typical gain and 1.1dB noise figure from 200-900MHz. This RFIC uses the latest Silicon Germanium HBT process.

The matte tin finish on Sirenza's lead-free package utilizes a post annealing process to mitigate tin whisker formation and is RoHS compliant per EU Directive 2002/95. This package is also manufactured with green molding compounds that contain no antimony trioxide or halogenated fire retardants.

Simplified Device Schematic



Product Features

- **Lead Free, RoHS Compliant & Green Package**
- **Low Power Consumption, 5.7mA @ 3.3V**
- **External Input Noise Match**
- **High Gain and Low Noise, 20dB and 1.1dB respectively @ 900MHz**
- **Operates from 2.7 to 3.3V**
- **Power Shutdown Capability using V_{PC}**
- **Small Package: SOT-363**

Applications

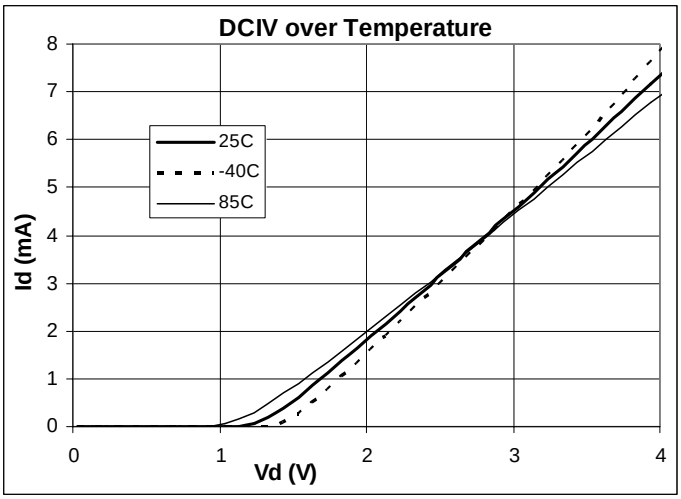
- **Low Power LNA for ISM, Cellular and Mobile Communications**

Symbol	Parameters	Units	Frequency	Min.	Typ.	Max.
S_{21}	Small Signal Gain	dB	200 MHz 450 MHz 900 MHz	 17	21 20 20	 23
P_{1dB}	Output Power at 1dB Compression	dBm	200 MHz 450 MHz 900 MHz		1.1 2.2 2.5	
IIP_3	Input Third Order Intercept Point	dBm	200 MHz 450 MHz 900 MHz		-3.1 -3.1 -3.1	
NF	Noise Figure	dBm	200 MHz 450 MHz 900 MHz		1.0 1.1 1.1	
S11	Input Return Loss	dBm	200 MHz 450 MHz 900 MHz		14 12 15	
S22	Output Return Loss	dBm	200 MHz 450 MHz 900 MHz		20 19 12	
S12	Reverse Isolation	dBm	200 MHz 450 MHz 900 MHz		24 25 27	
I_D	Device Operating Current	mA		4.8	5.7	6.6
R_{TH}, j-l	Thermal Resistance (junction - lead)	°C/W			TBD	
Test Conditions:	Vcc = 3.3V	I_D = 5.7mA Typ.	IIP_3 Tone Spacing = 1MHz, Pout per tone = -15 dBm			
	T_L = 25°C	$Z_S = Z_L$ = 50 Ohms	Different Application Circuit per Band			

Absolute Maximum Ratings

Parameter	Absolute Limit
Max Device Current (I_D)	8mA
Max Device Voltage (V_D)	4 V
Max. RF Input Power	-10 dBm
Max. Junction Temp. (T_J)	+150°C
Operating Temp. Range (T_L)	-40°C to +85°C
Max. Storage Temp.	+150°C

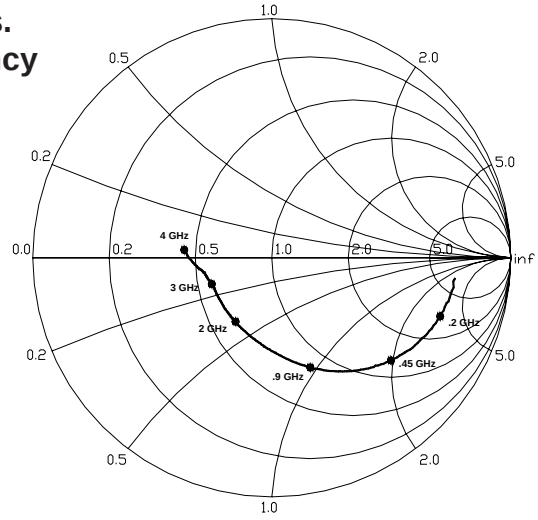
Operation of this device beyond any one of these limits may cause permanent damage. For reliable continuous operation, the device voltage and current must not exceed the maximum operating values specified in the table on page one.
Bias Conditions should also satisfy the following expression:
$I_D V_D < (T_J - T_L) / R_{TH, j-l}$ $T_L=T_{LEAD}$



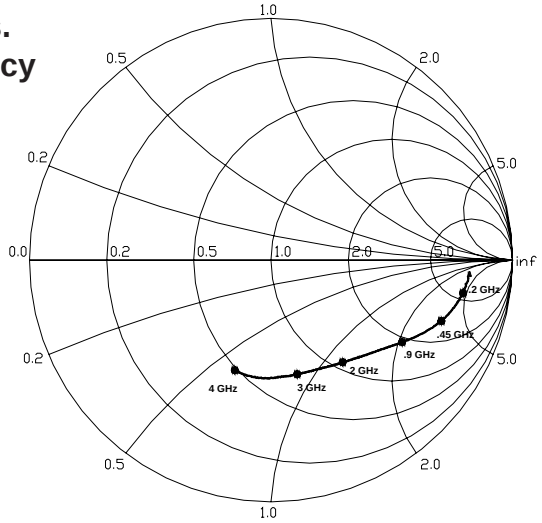
Typical Performance - De-embedded S-parameters

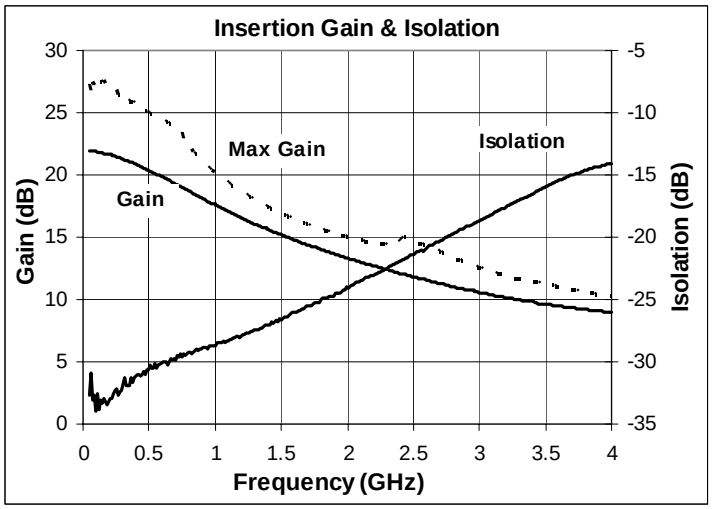
Note: S-parameters are de-embedded to the device leads with ZS=ZL=50Ω. The device was mounted on eval. board 125390-B and grounded like 900MHz application circuit. De-embedded S-parameters can be downloaded from our website (www.sirenza.com)

S11 Vs. Frequency



S22 Vs. Frequency

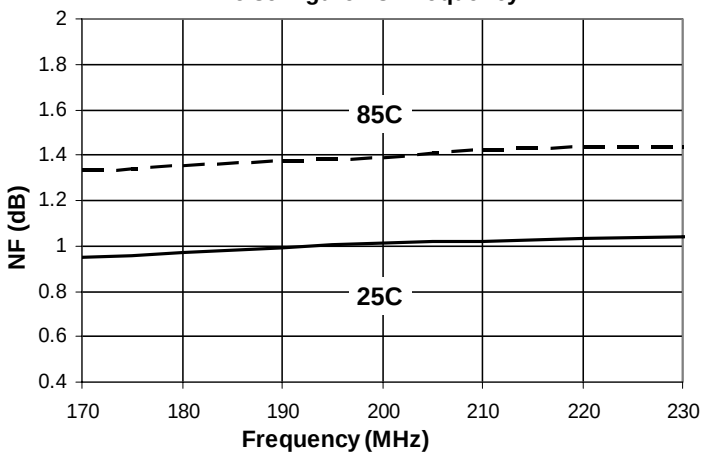




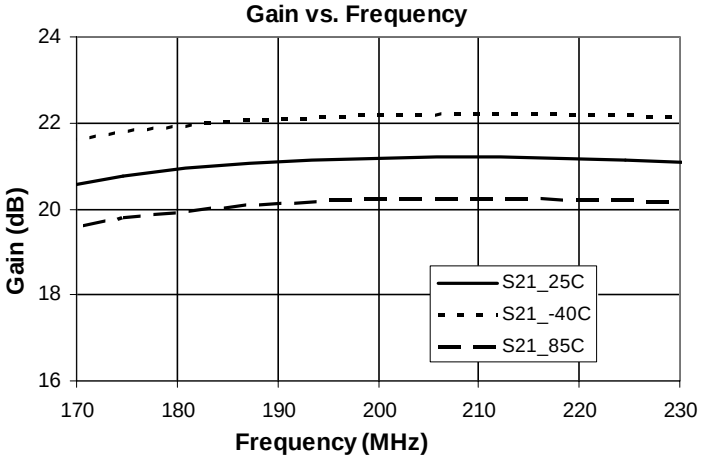
200 MHz Application Circuit Data, V_{cc}= 3.3V, I_D= 5.7mA

Note: Tuned for NF

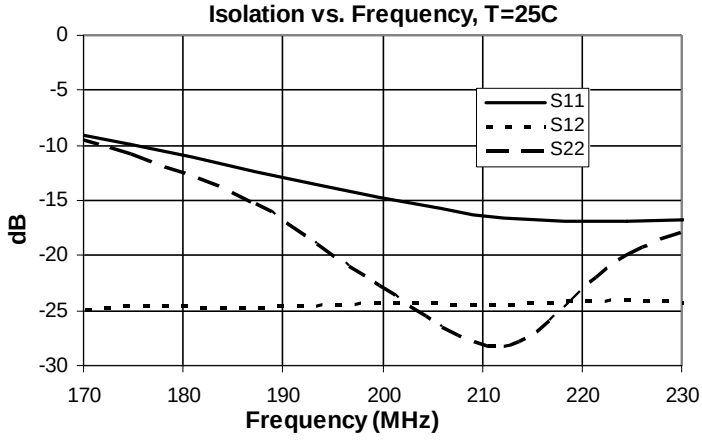
Noise Figure vs. Frequency



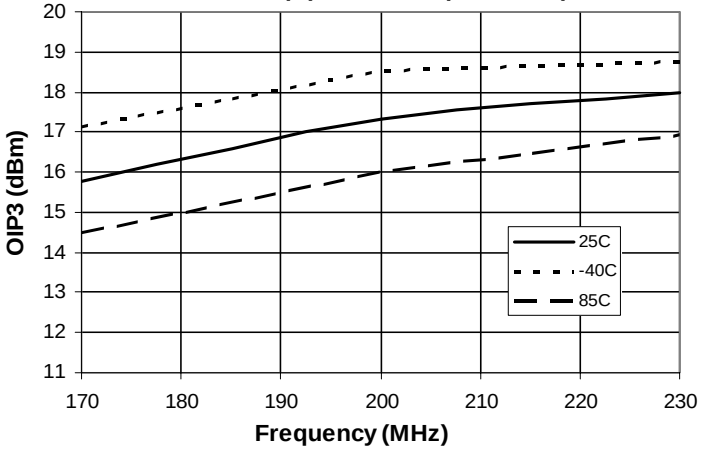
Gain vs. Frequency



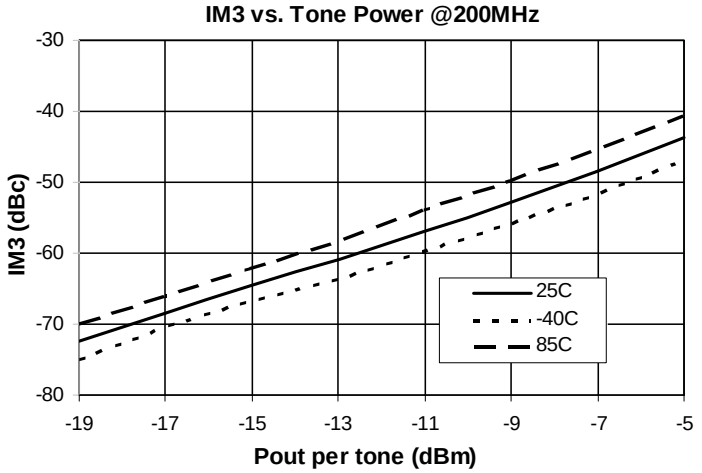
Input/Output Return Loss, Isolation vs. Frequency, T=25C



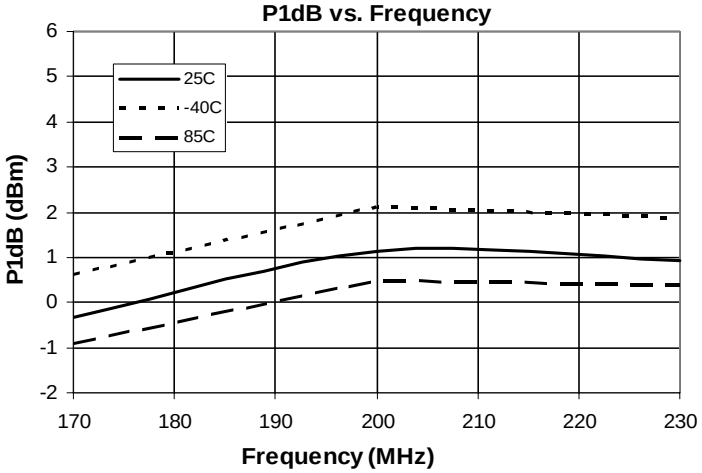
OIP3 vs. Freq. (-15dBm Output Tones)



IM3 vs. Tone Power @200MHz

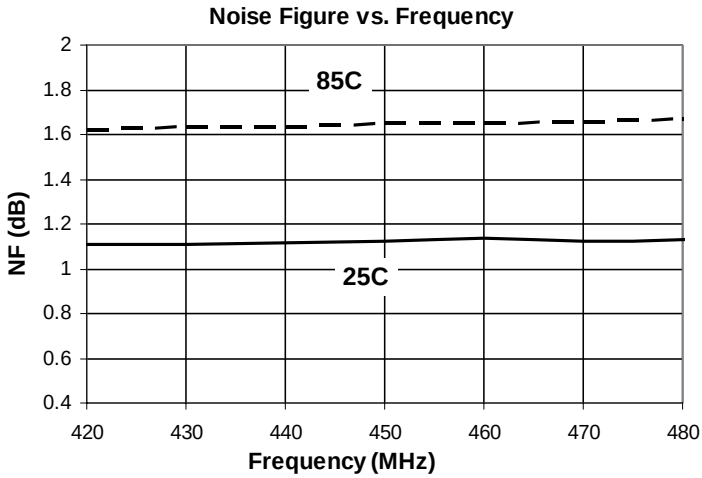


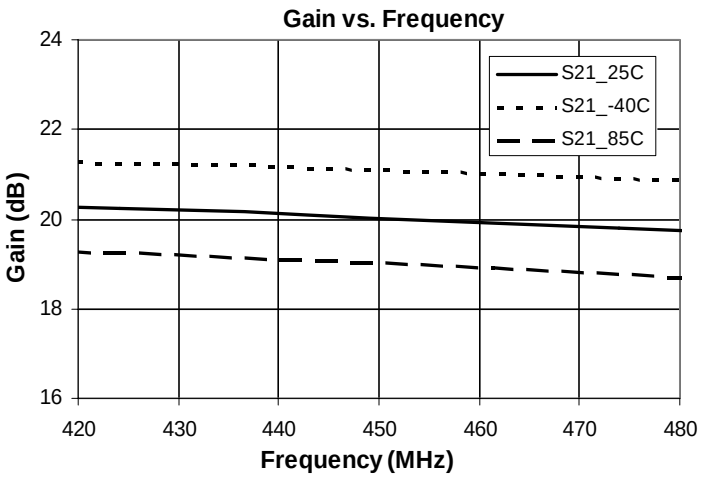
P1dB vs. Frequency

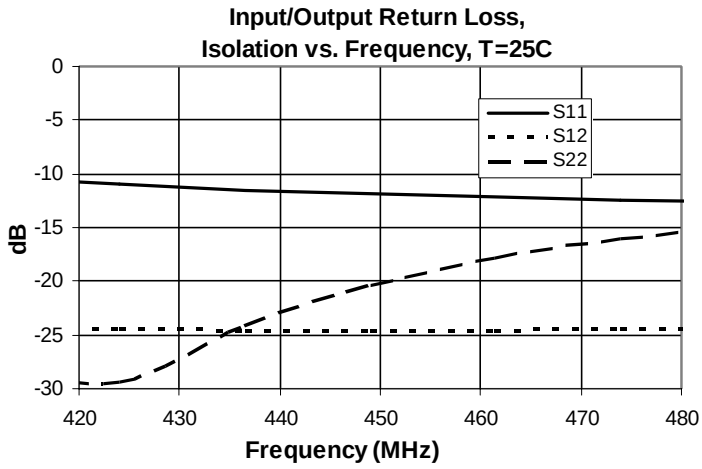


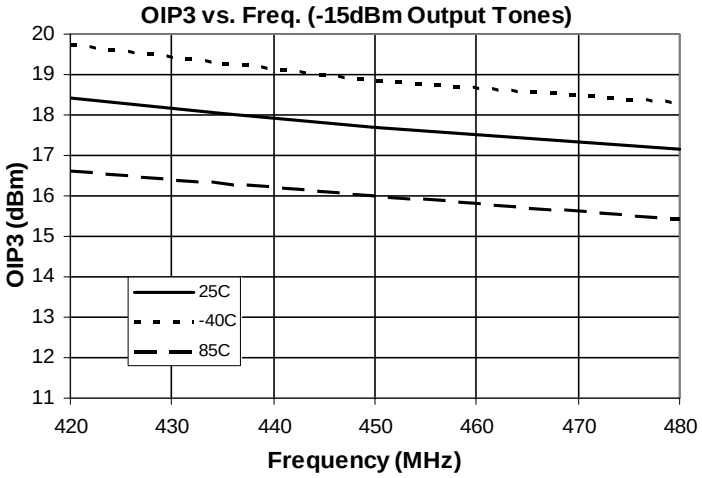
450 MHz Application Circuit Data, V_{CC}= 3.3V, I_D= 5.7mA

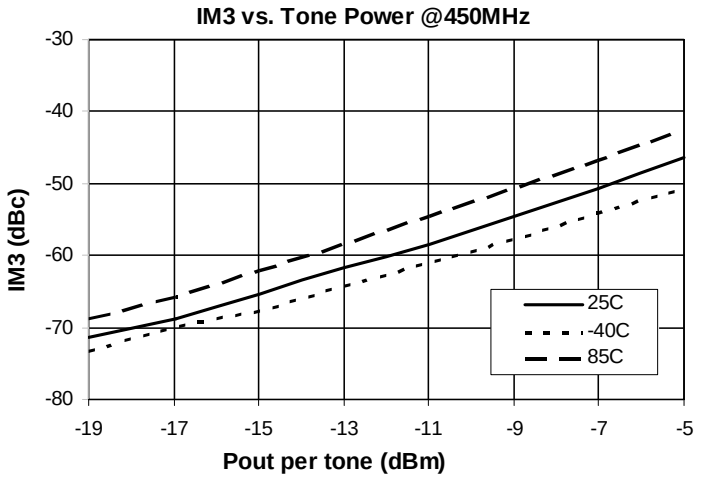
Note: Tuned for NF

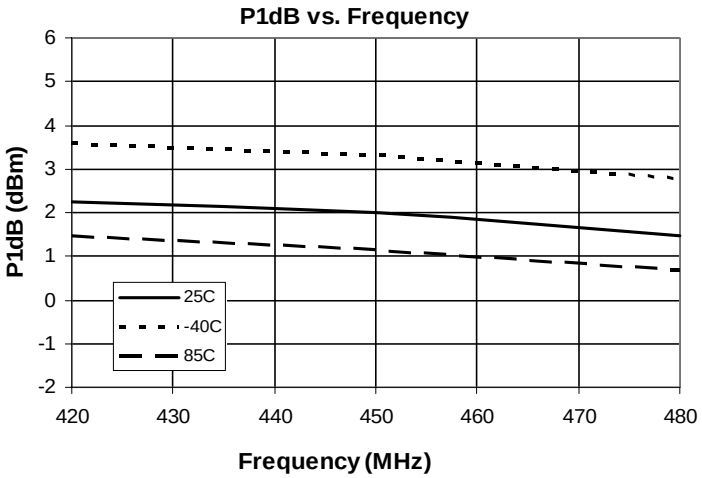






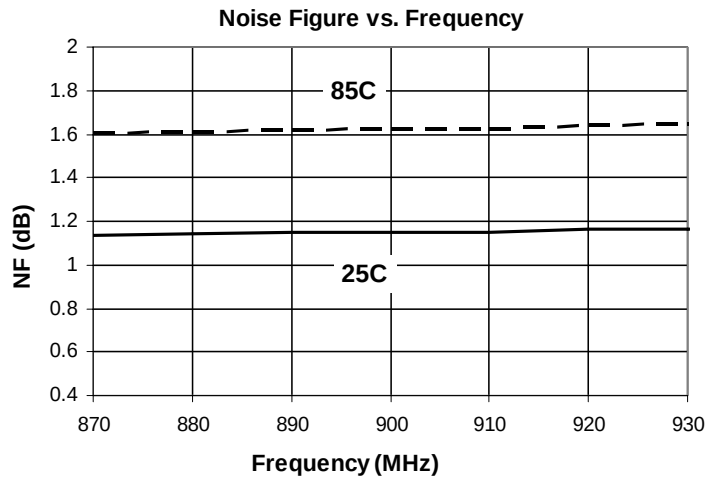


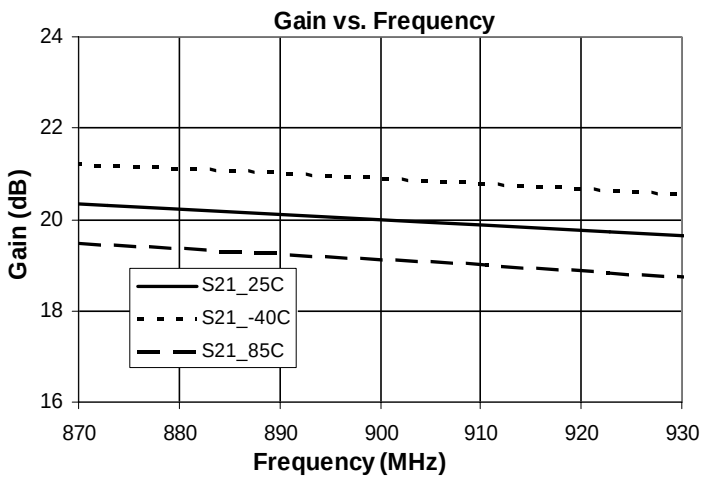


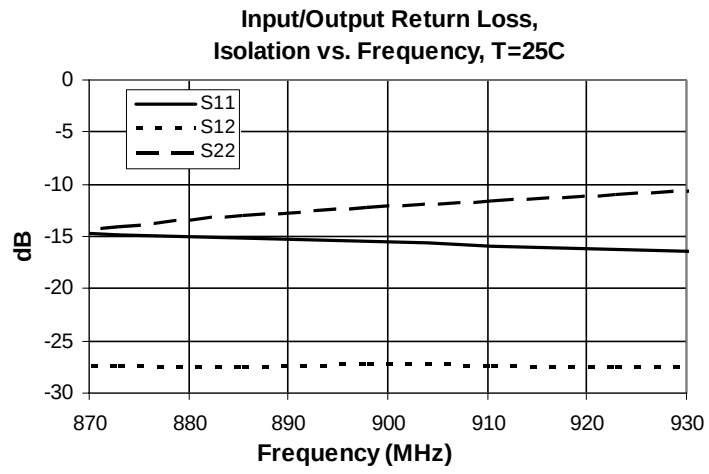


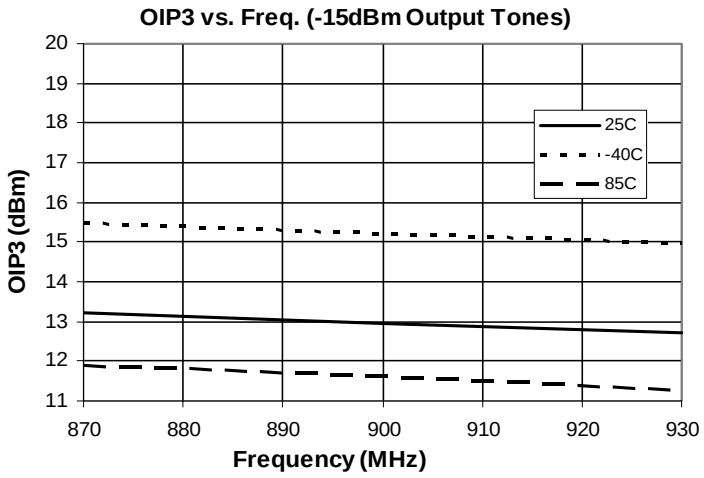
900 MHz Application Circuit Data, V_{cc}= 3.3V, I_D= 5.7mA

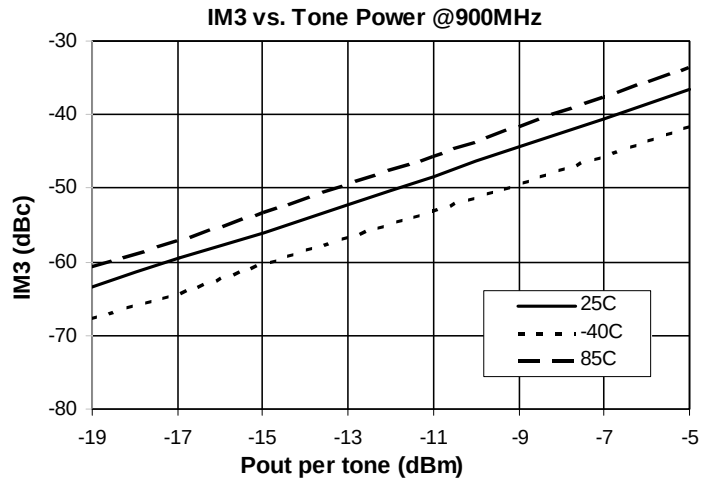
Note: Tuned for NF

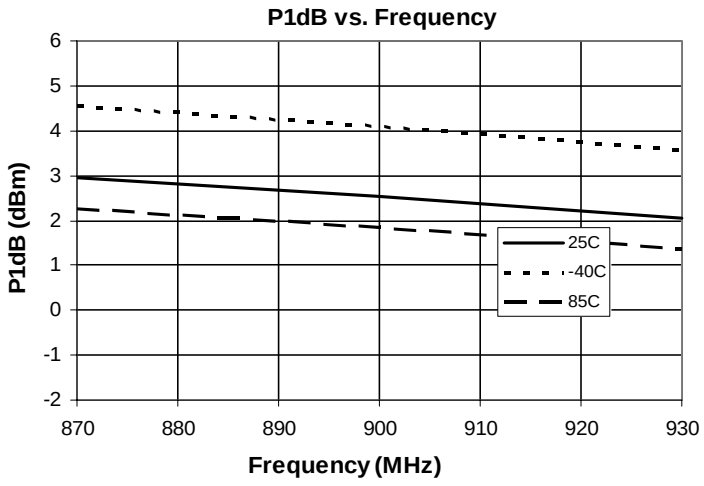




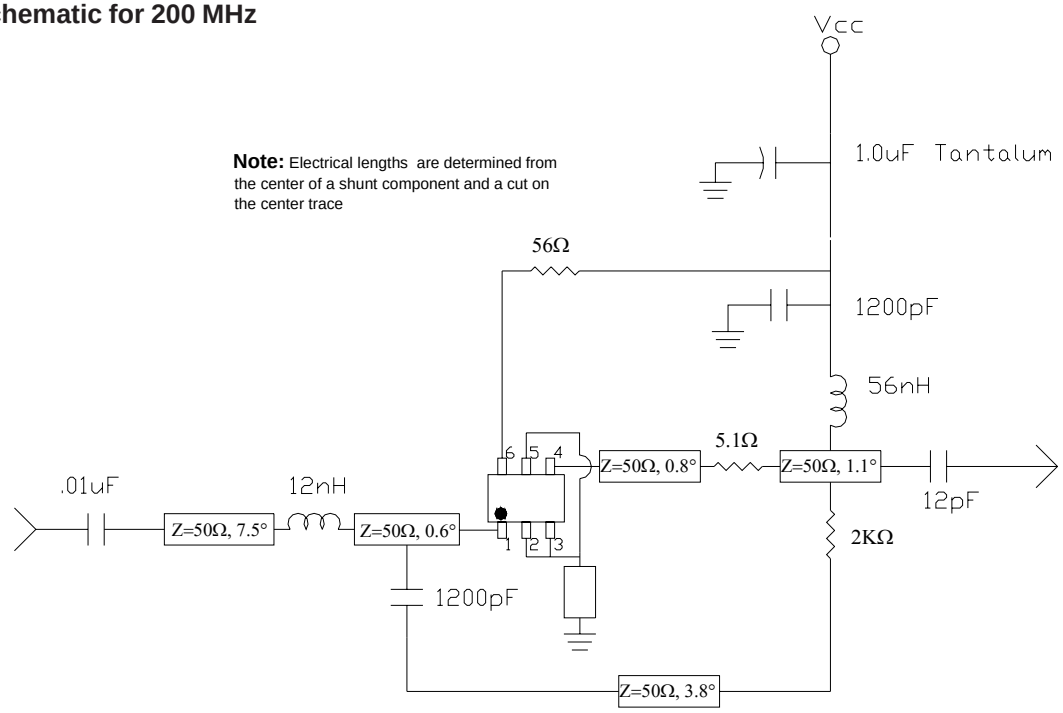






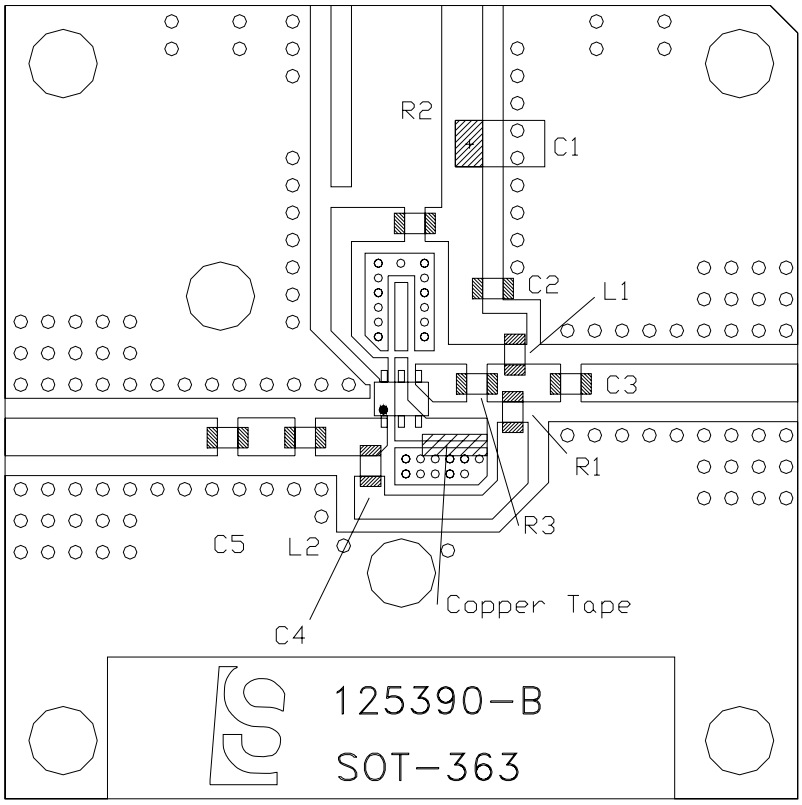


Application Schematic for 200 MHz



Note: Electrical lengths are determined from the center of a shunt component and a cut on the center trace

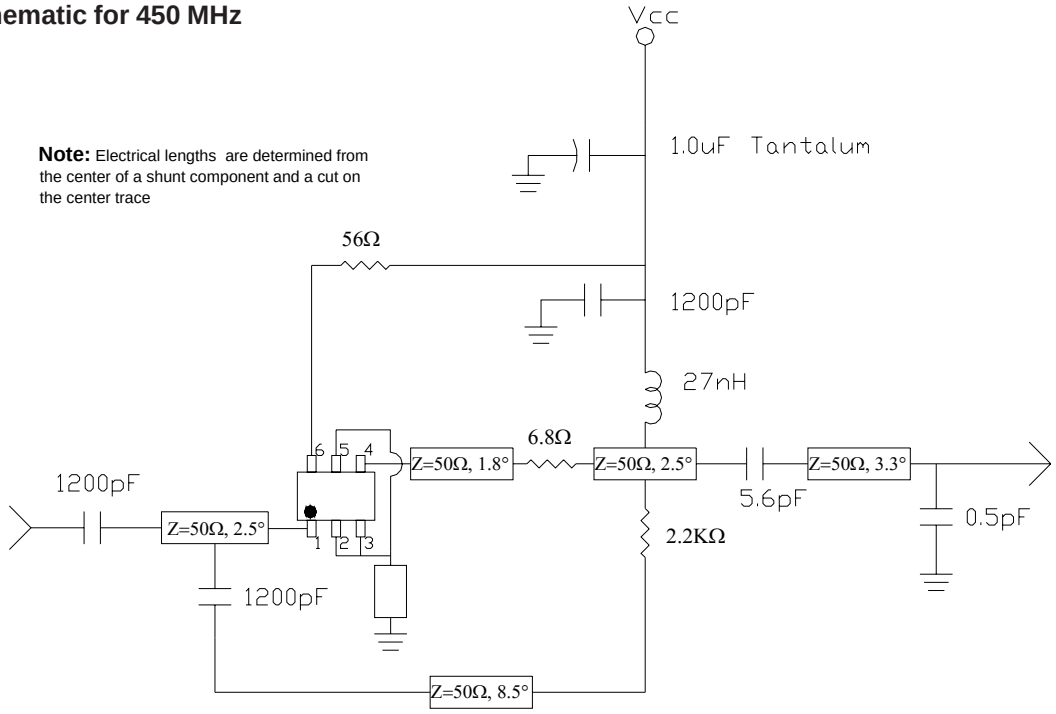
Evaluation Board Layout for 200 MHz



Bill of Materials

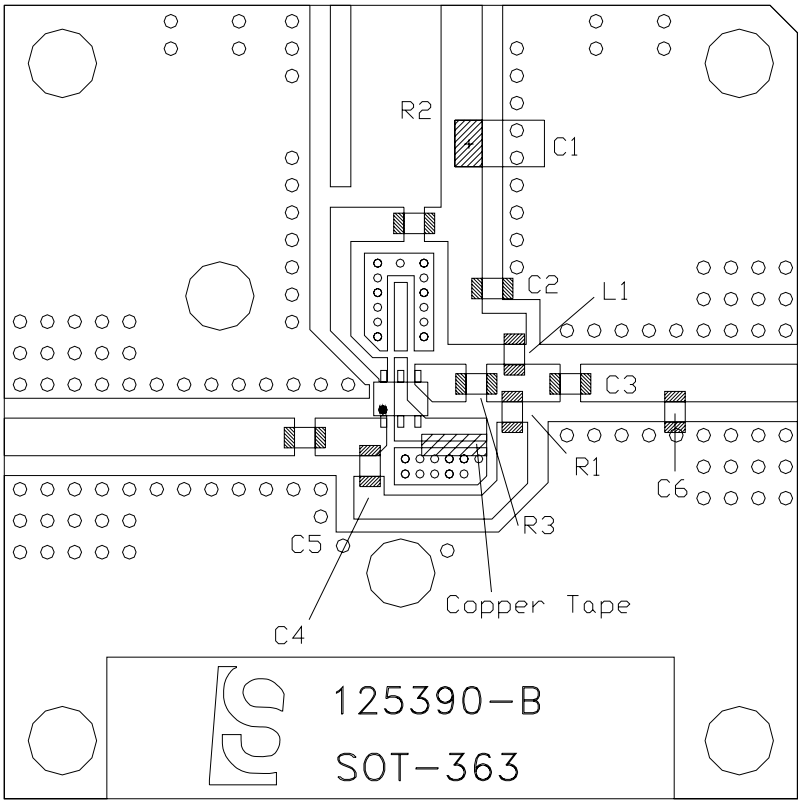
C1	1.0uF Tantalum capacitor
C2	1200pF 0603 ceramic capacitor
C3	12pF 0603 ceramic capacitor
C4	1200pF 0603 ceramic capacitor
C5	.01uF 0603 ceramic capacitor
L1	LL1608-FS56NJ Toko 56nH
L2	LL1608-FS12NJ Toko 12nH
R1	2KΩ 0603 res (5%)
R2	56Ω 0603 res (5%)
R3	5.1Ω 0603 res (5%)
Connectors	2x PSF-S01-1mm GigaLane Co.
Heat sink	EEF-102059
PCB	125390-B

Application Schematic for 450 MHz



Note: Electrical lengths are determined from the center of a shunt component and a cut on the center trace

Evaluation Board Layout for 450 MHz

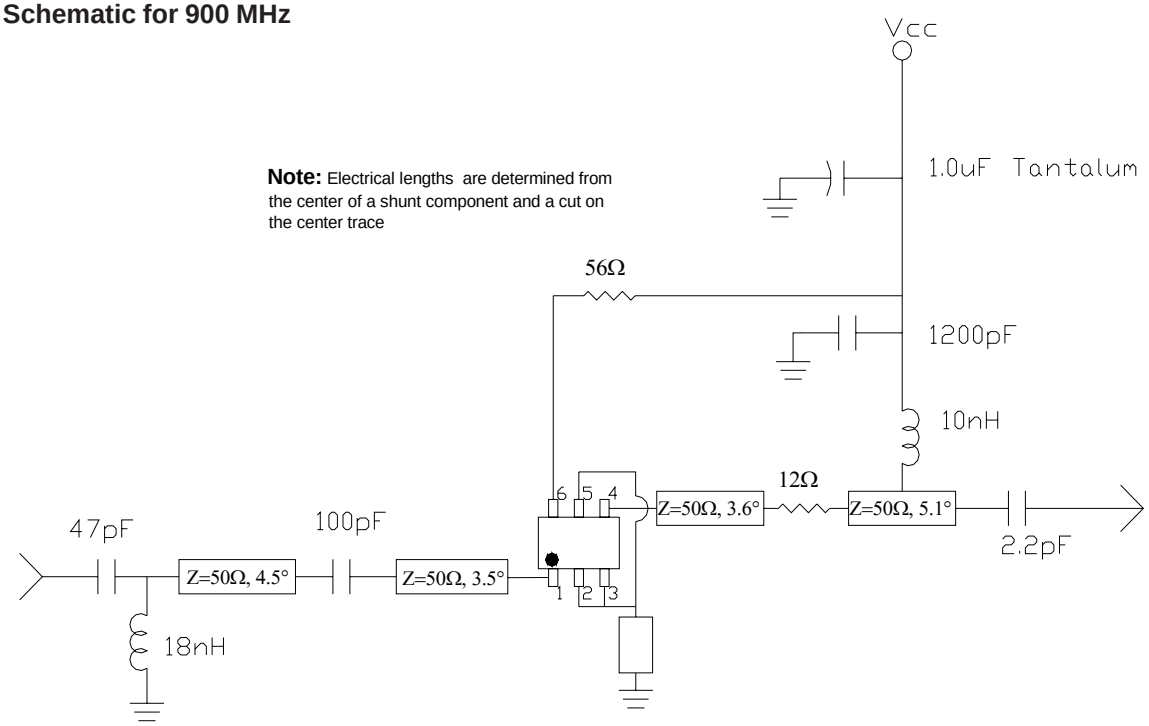


Bill of Materials

C1	1.0uF Tantalum capacitor
C2	1200pF ceramic 0603 capacitor
C3	5.6pF ceramic 0603 capacitor
C4	1200pF ceramic 0603 capacitor
C5	1200pF ceramic 0603 capacitor
C6	0.5pF ceramic 0603 capacitor
L1	LL1608-FS27NJ Toko 27nH
R1	2.2KΩ 0603 res (5%)
R2	56Ω 0603 res (5%)
R3	6.8Ω 0603 res (5%)

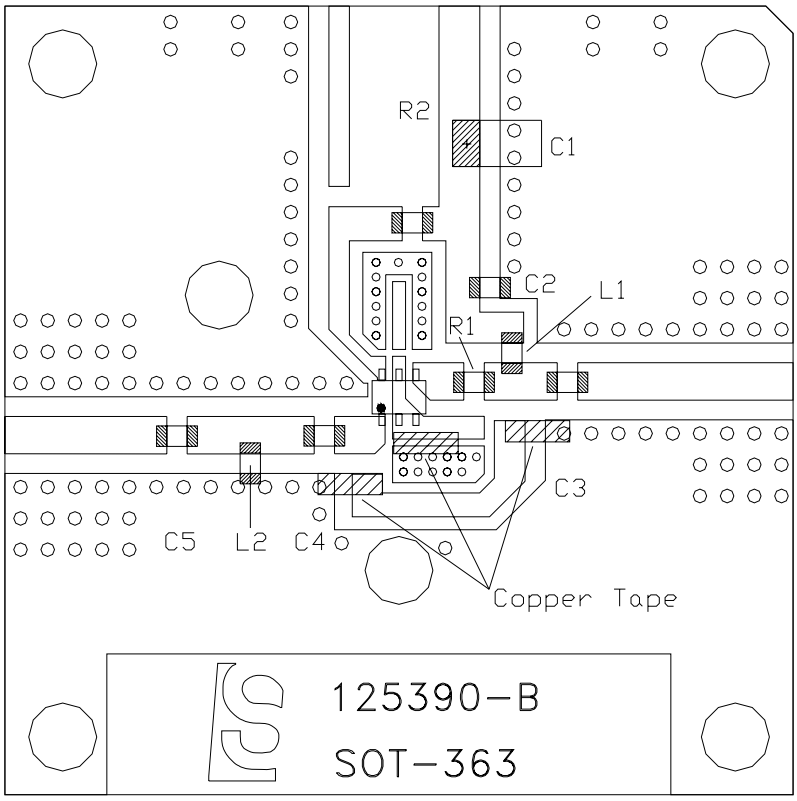
Connectors 2x PSF-S01-1mm GigaLane Co.
Heat sink EEF-102059
PCB 125390-B

Application Schematic for 900 MHz



Note: Electrical lengths are determined from the center of a shunt component and a cut on the center trace

Evaluation Board Layout for 900 MHz



Bill of Materials

C1	1.0uF Tantalum capacitor
C2	1200pF ceramic 0603 capacitor
C3	2.2pF ceramic 0603 capacitor
C4	100pF ceramic 0603 capacitor
C5	47pF ceramic 0603 capacitor
L1	LL1608-FS10NJ Toko 10nH
L2	LL1608-FS18NJ Toko 18nH
R1	12Ω 0603 res (5%)
R2	56Ω 0603 res (5%)

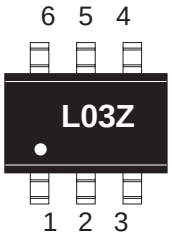
Connectors	2x PSF-S01-1mm GigaLane Co.
Heat sink	EEF-102059
PCB	125390-B

Pin #	Function	Description
1	RF IN	RF input pin. This pin requires the use of an external DC blocking capacitor and matching components as shown in the application schematics.
2, 5	GND	Connect to ground per application circuit drawing. Series feedback used to improve IRL
3	Gnd	Gnd for active bias tied internally to pin 2 & 5
4	RF OUT/ V_D	RF output and bias pin. Bias should be supplied to this pin through an external RF choke. (See application circuits)
6	V_{PC}	V_{PC} is the bias control pin for the active bias network.

Part Number Ordering Information

Part Number	Reel Size	Devices / Reel
SGL-0363Z	7"	3000

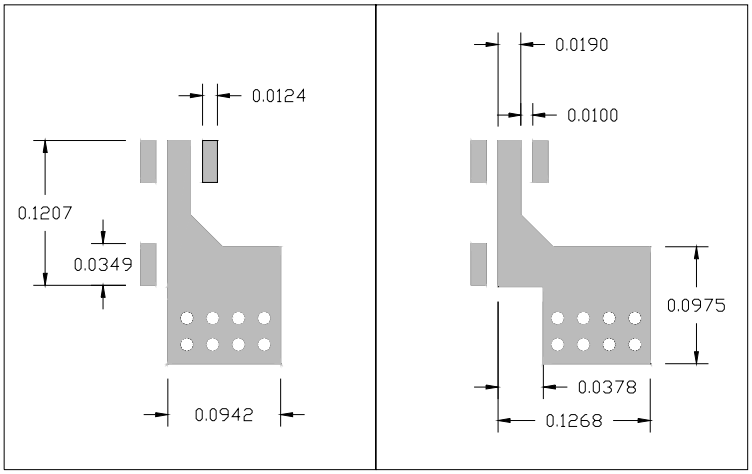
Part Identification



Caution: ESD sensitive
Appropriate precautions in handling, packaging and testing devices must be observed.

MSL (Moisture Sensitivity Level) **Rating: Level 1**

Suggested Pad Layouts



900MHz Layout **200MHz & 400MHz Layout**

Nominal Package Dimensions

Dimensions in inches [millimeters]
Refer to drawing posted at *www.sirenza.com* for tolerances.